

DESCRIPTION

The AO2325 have a high gain-bandwidth product of 11MHz, a slew rate of 9V/µs, and a quiescent current of 1.1mA per amplifier at 5V.

The AO2325 is designed to provide optimal performance in low voltage and low noise systems. They provide rail-to-rail output swing into heavy loads. The input common mode voltage range includes ground, and the maximum input offset voltage is 3.5mV for AO2325.

They are specified over the extended industrial temperature range (-40°C to +125°C). The operating range is from 2.1V to 5.5V.

The AO2325 is available in DFN8(2x2) package.

FEATURES

- Single-Supply Operation from +2.1V ~ +5.5V
- Rail-to-Rail Input / Output
- Gain-Bandwidth Product: 11MHz (Typ.)
- Low Input Bias Current: 1pA (Typ.)
- Low Offset Voltage: 3.5mV (Max.)
- High Slew Rate: 9V/μs
- Settling Time to 0.1% with 2V Step: 0.3μs
- Low Noise: 8nV/√HZ@10kHZ
- Quiescent Current: 1.1mA per Amplifier (Typ.)
- Operating Temperature: -40°C ~ +125°C

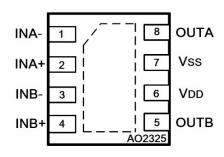
APPLICATION

- Sensors
- Active Filters
- Cellular and Cordless Phones
- Laptops and PDAs
- Audio
- Handheld Test Equipment
- Battery-Powered Instrumentation
- A/D Converters

ORDERING INFORMATION

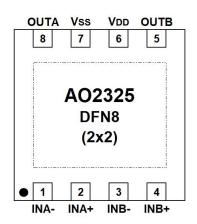
Package Type	Part Number		
DFN8		AO2325J8R	
(2x2)	J8	AO2325J8VR	
SPQ: 3,000pcs/Reel			
Niete	V: Halogen free Package		
Note	R: Tape & Reel		
AiT provides all RoHS products			

TYPICAL APPLICATION



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PIN DESCRIPTION



DFN8(2x2), J8 Top View

Pin#	Symbol	Functions	
1	INA-	Inverting Input, Channel A	
2	INA+	Noninverting Input, Channel A	
3	INB-	Inverting Input, Channel B	
4	INB+	Noninverting Input, Channel B	
5	OUTB	Output, Channel B	
6	V_{DD}	Positive Power Supply Input.	
7	Vss	Ground or Negative Power Supply Input.	
8	OUTA	Output, Channel A	

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ABSOLUTE MAXIMUM RATINGS

T_A=+25°C,unless otherwise specified

Power Supply Voltage (V _{DD} to V _{SS})		-0.5V ~ +7.5V	
Analog Input Voltage (IN+ or IN-)		V_{SS} -0.5V ~ V_{DD} +0.5V	
PDB Input Voltage		Vss -0.5V ~ +7V	
Operating Temperature Range		-40°C ~ +125°C	
Junction Temperature		+160°C	
Storage Temperature Range		-55°C ~ +150°C	
Lead Temperature (soldering, 10sec)		+260°C	
ESD Susceptibility	Human Body Mode	8KV	
	Machine Mode	400V	

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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ELECTRICAL CHARACTERISTICS

At Vs=5V, T_A = +25°C, V_{CM} = $V_S/2$, R_L = 600 Ω , unless otherwise noted.

Parameter	Symbol	Conditio	ns	Min.	Тур.	Max.	Unit
INPUT CHARACTERISTIC	S						
Input Offset Voltage	Vos		+25°C	-	0.8	3.5	mV
·	V 05		-40°C ~ +125°C	-	-	4.6	111 V
Input Bias Current	lΒ			-	1.0	-	pА
Input Offset Current	los			-	1.0	-	pА
Input Common Mode Voltage Range	V_{CM}	V _S = 5.5V		-	-0.1~ +5.6	-	V
Common Mode Rejection		$V_{S} = 5.5V$,	+25°C	65	82	-	dB
Ratio	CMRR	$V_{CM} = -0.1V \text{ to } 4V$	-40°C ~ +125°C	63	-	-	uБ
ratio		$V_S = 5.5V$, $V_{CM} = -0.1$	V to 5.6V	-	75	-	dB
		$R_L = 600\Omega$,	+25°C	80	90	-	dB
Open-Loop Voltage Gain	A_{OL}	$V_0 = 0.15V \text{ to } 4.85V$	-40°C ~ +125°C	68	-	-	ub
		$R_L = 10k\Omega, V_0 = 0.05$	V to 4.95V	-	108	-	dB
Input Offset Voltage Drift	ΔVos/Δτ			-	2.4	-	μV/°C
OUTPUT CHARACTERIST	ICS						
Output Voltage Swing		$R_L = 600\Omega$		-	0.100	-	V
from Rail		$R_L = 10k\Omega$		-	0.015	-	V
Output Current	Іоит		+25°C -40°C ~ +125°C	55 38	70	-	mA
Closed-Loop Output Impedance		f=100kHz, G=1		-	7.5	-	Ω
POWER SUPPLY							
I OWER OOI I ET			+25°C	2.1	_	5.5	
Operating Voltage Range			-40°C ~ +125°C	2.1	+ -	5.5	V
Power Supply Rejection		V _S = +2.5V to +5.5V	+25°C	74	91	0.0	
Ratio	PSRR	$V_{\text{CM}} = (-V_{\text{S}}) + 0.5V$	-40°C ~ +125°C	68	91		dB
Quiescent		VCM = (-VS) + 0.3V	+25°C	-	1.10	1.50	
Current/Amplifier	ΙQ	I _{OUT} = 0	-40°C ~ +125°C	_	1.10	1.85	mA
IDYNAMIC PERFORMANO	:F		40 0 1120 0			1.00	1
Gain-Bandwidth Product	G _{BP}	R _L =10kΩ, C _L =100pF		_	11	_	MHz
Phase Margin	Фо	R _L =0kΩ, C _L =100pF		_	51	_	Degrees
Full Power Bandwidth	- Ψ∪ Bwp	< 1% distortion, R _L =6	S000		400		kHz
Slew Rate	SR	G=+1, 2V Step, R _L =1			9		1
Settling Time to 0.1%		G=+1, 2V Step, RL=1		-	0.3		V/µs
<u> </u>	t _s	·		-			μs
Overload Recovery Time		V _{IN} xGain=V _S , R _L = 60	077	-	1.5	-	μs
NOISE PERFORMANCE		f = 11/LI=			44 E		n\/ /
Voltage Noise	e n	f = 1kHz		_	11.5	-	nV /
Density		f = 10kHz		-	8.0	_	\sqrt{HZ}

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TYPICAL PERFORMANCE CHARACTERISTICS

At Vs=5V, $T_A = +25^{\circ}C$, $V_{CM} = V_S/2$, $R_L = 600\Omega$, unless otherwise noted.

Fig.1 Large-Signal Step Response

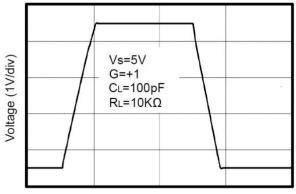
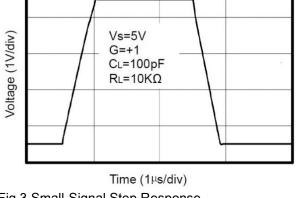


Fig.3 Small-Signal Step Response



Time (1µs/div) Fig.4 Small-Signal Step Response

Voltage (500mV/div)

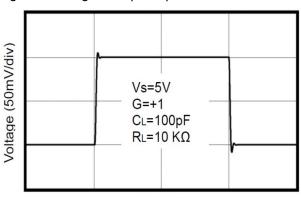
Fig.2 Large-Signal Step Response

Vs=2.5V

C_L=100pF

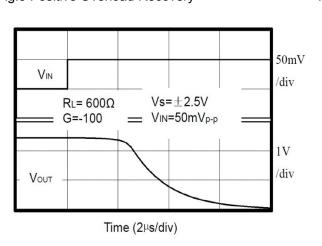
RL=10 KΩ

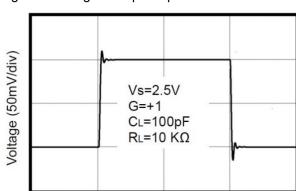
G=+1



Time (1µs/div)

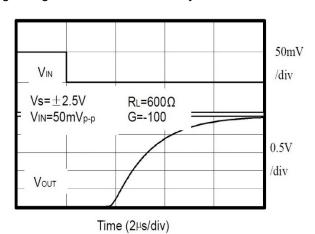
Fig.5 Positive Overload Recovery





Time (1µs/div)

Fig.6 Negative Overload Recovery



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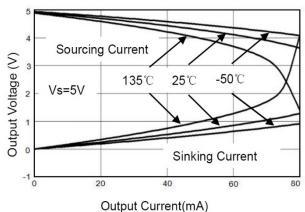


Fig.9 Input Voltage Noise Spectral Density vs. Frequency

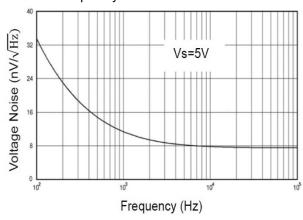


Fig.11 CMRR vs. Frequency

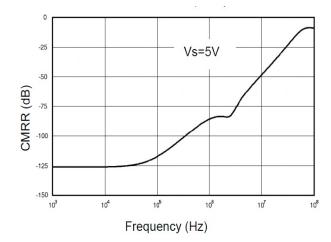


Fig. 8 Supply Current vs. Temperature

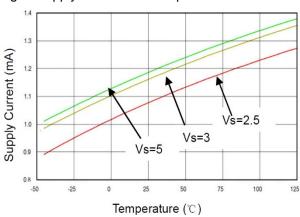


Fig.10 Open Loop Gain, Phase Shift vs. Frequency

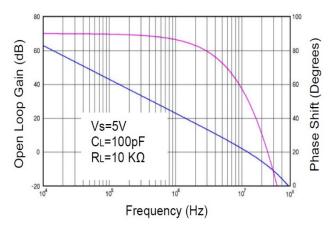
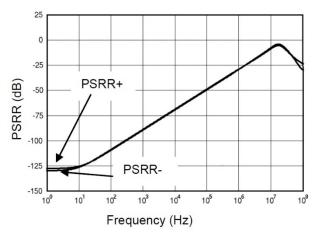


Fig.12 PSRR vs. Frequency



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11MHZ CMOS RAIL-TO-RAIL IO OPAMPS

DETAILED INFORMATION

The AO2325 op amp is unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the AO2325 series packages save space on printed circuit boards and enable the design of smaller electronic products.

Power Supply Bypassing and Board Layout

The AO2325 operates from a single 2.1V to 5.5V supply or dual ± 1.05 V to ± 2.75 V supplies. For best performance, a $0.1\mu F$ ceramic capacitor should be placed close to the V_{DD} pin in single supply operation. For dual supply operation, both V_{DD} and V_{SS} supplies should be bypassed to ground with separate $0.1\mu F$ ceramic capacitors.

Low Supply Current

The low supply current (typical 1.1mA per channel) of the AO2325 will help to maximize battery life. AO2325 is ideal for battery powered systems.

Operating Voltage

The AO2325 operates under wide input supply voltage (2.1V to 5.5V). In addition, all temperature specifications apply from -40 °C to +125 °C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-lon battery lifetime.

Rail-to-Rail Input

The input common-mode range of the AO2325 extends 100mV beyond the supply rails (V_{SS} -0.1V to V_{DD} +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of AO2325 can typically swing to less than 2mV from supply rail in light resistive loads (>100k Ω), and 15mV of supply rail in moderate resistive loads (10k Ω).

Capacitive Load Tolerance

The AO2325 is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation.

If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Fig13. Shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

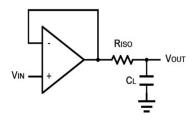


Fig13. Indirectly Driving a

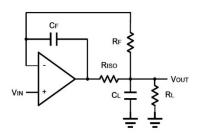
Capacitive Load using Isolation Resistor

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The bigger the R_{ISO} resistor value, the more stable V_{OUT} will be. However, if there is a resistive load R_L in parallel with the capacitive load, a voltage divider (proportional to R_{ISO} / R_L) is formed, this will result in a gain error. The circuit in Fig 14. is an improvement to the one in Fig 13. R_F provides the DC accuracy by feed-forward the V_{IN} to R_L. C_F and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of C_F. This in turn will slow down the pulse response.



Capacitive Load With DC Accuracy

Differential Amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal.

Fig 15. shown the differential amplifier using AO2325.

$$V_{\text{OUT}} = \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_4}{R_1} V_{IN} - \frac{R_2}{R_1} V_{IP} + \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_3}{R_1} V_{REF}$$

If the resistor ratios are equal (i.e. R₁=R₃ and R₂=R₄), then

$$V_{OUT} = \frac{R_2}{R_1} (V_{IP} - V_{IN}) + V_{REF}$$

VIN R3 VOUT

Fig 15. Differential Amplifier

Low Pass Active Filter

The low pass active filter is shown in Fig 16.

The DC gain is defined by $-R_2 / R_1$. The filter has a

-20dB/decade roll-off after its corner frequency f_C=1/(2πR₃C₁)

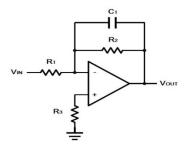


Fig 16. Low Pass Active Filter

Instrumentation Amplifier

The triple AO2325 can be used to build a three-op-amp instrumentation amplifier as shown in Fig 17.

The amplifier in Fig 17. is a high input impedance differential amplifier with gain of R_2 / R_1 .

The two differential voltage followers assure the high input impedance of the amplifier.

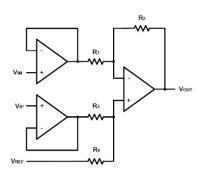
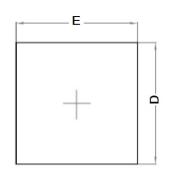


Fig 17. Instrument Amplifier

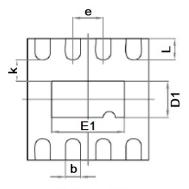
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PACKAGE INFORMATION

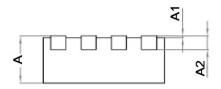
Dimension in DFN8(2x2) (Unit: mm)



Top View



Bottom View



Side View

Symbol	Millimeters		
Symbol	Min	Max	
А	0.800	0.900	
A1	0.000	0.050	
A2	0.153	0.253	
b	0.180	0.300	
D	1.900	2.100	
E	1.900	2.100	
D1	0.500	0.700	
E1	1.100	1.300	
е	0.500 BSC		
k	0.200	-	
L	0.250	0.450	

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